

# 2SB791(K)

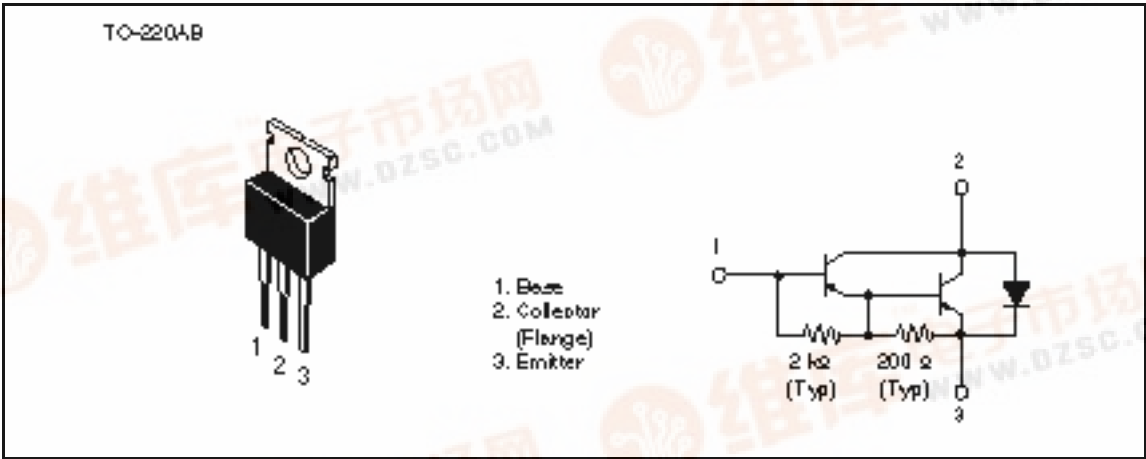
Silicon PNP Epitaxial

HITACHI

## Application

Medium speed and power switching complementary pair with 2SD970(K)

## Outline



## Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rating	Unit
Collector to base voltage	$V_{CBO}$	-120	V
Collector to emitter voltage	$V_{CEO}$	-120	V
Emitter to base voltage	$V_{EBO}$	-7	V
Collector current	$I_C$	-8	A
Collector peak current	$I_{C(peak)}$	-12	A
Collector power dissipation	$P_C^{*1}$	40	W
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

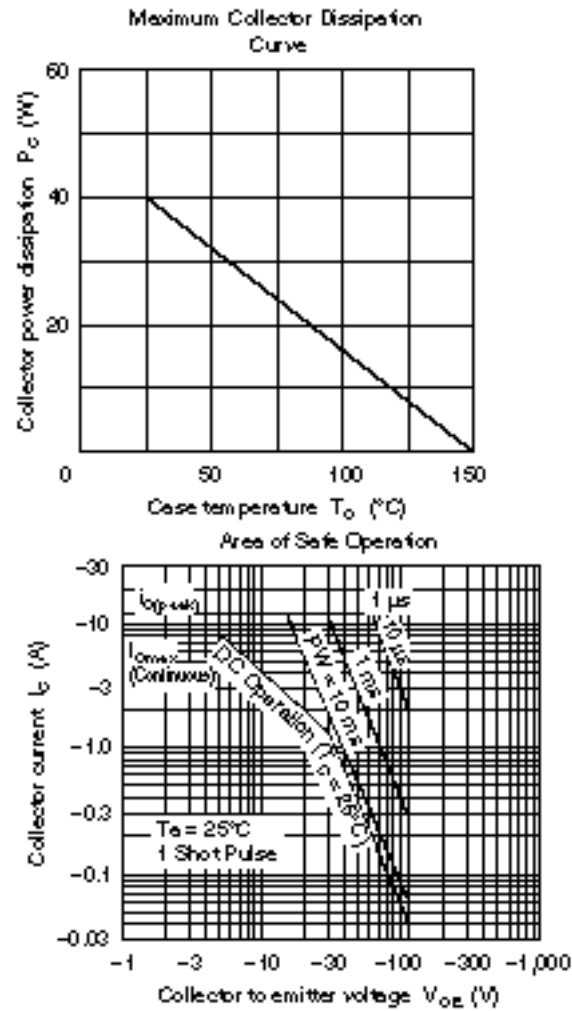
Note: 1. Value at  $T_c = 25^\circ\text{C}$

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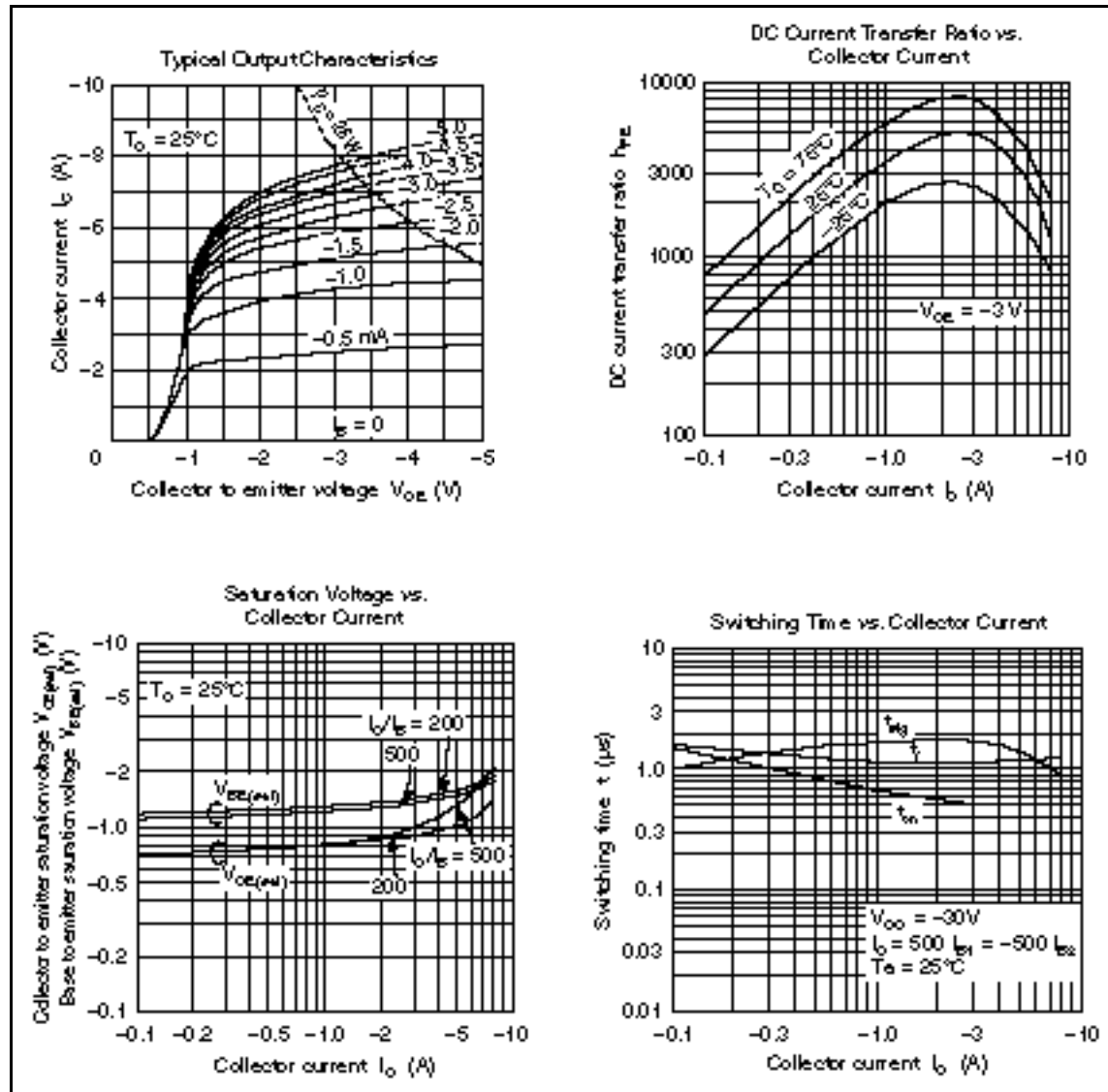
### Electrical Characteristics (Ta = 25°C)

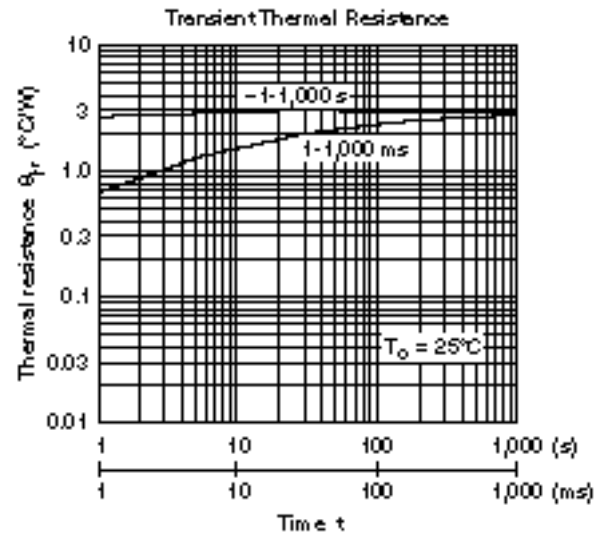
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	-120	—	—	V	$I_C = -25 \text{ mA}$ , $R_{BE} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	-7	—	—	V	$I_E = -50 \text{ mA}$ , $I_C = 0$
Collector cutoff current	$I_{CBO}$	—	—	-100	$\mu\text{A}$	$V_{CB} = -120 \text{ V}$ , $I_E = 0$
	$I_{CEO}$	—	—	-10	$\mu\text{A}$	$V_{CE} = -100 \text{ V}$ , $R_{BE} =$
DC current transfer ratio	$h_{FE}$	1000	—	20000		$V_{CE} = -3 \text{ V}$ , $I_C = -4 \text{ A}^{*1}$
Collector to emitter saturation voltage	$V_{CE(sat)(1)}$	—	—	-1.5	V	$I_C = -4 \text{ A}$ , $I_B = -8 \text{ mA}^{*1}$
	$V_{CE(sat)(2)}$	—	—	-3.0	V	$I_C = -8 \text{ A}$ , $I_B = -80 \text{ mA}^{*1}$
Base to emitter saturation voltage	$V_{BE(sat)(1)}$	—	—	-2.0	V	$I_C = -4 \text{ A}$ , $I_B = -8 \text{ mA}^{*1}$
	$V_{BE(sat)(2)}$	—	—	-3.5	V	$I_C = -8 \text{ A}$ , $I_B = -80 \text{ mA}^{*1}$
Turn on time	$t_{on}$	—	0.5	—	$\mu\text{s}$	$I_C = -4 \text{ A}$ , $I_{B1} = I_{B2} = -8 \text{ mA}$
Storage time	$t_{stg}$	—	1.6	—	$\mu\text{s}$	
Fall time	$t_f$	—	1.5	—	$\mu\text{s}$	

Note: 1. Pulse test



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# HITACHI

### Hitachi, Ltd.

Semiconductor & IC Div.

Nippon Bldg., 2-6-2, Ohite-machi, Chiyoda-ku, Tokyo 100, Japan

Tel Tokyo (03) 3270-2111

Fax (03) 3270-5109

For further information write to:

Hitachi America, Ltd.

Semiconductor & IC Div.

2000 Sierra Point Parkway

Brisbane, CA 94005-4835

U.S.A.

Tel 415-589-8300

Fax 415-583-4207

Hitachi Europe GmbH

Electronic Components Group

Continental Europe

Danewer Straße 3

D-85622 Feldkirchen

München

Tel 089-9 94 80-0

Fax 089-9 29 30 00

Hitachi Europe Ltd.

Electronic Components Div.

Northern Europe Headquarters

Whitebrook Park

Lower Cookham Road

M Maidenhead

Berkshire SL6 8YA

United Kingdom

Tel 0628-585000

Fax 0628-778322

Hitachi Asia Pte. Ltd.

45 Collyer Quay #20-00

Hitachi Tower

Singapore 0104

Tel 535-2100

Fax 535-1533

Hitachi Asia (Hong Kong) Ltd.

Unit 705, North Tower,

World Finance Centre

Harbour City, Canton Road

Tsim Sha Tsui, Kowloon

Hong Kong

Tel 27352218

Fax 27308074